NSN 5961-01-309-8673

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Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

0.300 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204aa

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 80.0 drain to gate voltage and 20.0 gate to source voltage

Current Rating Per Characteristic:

20.00 amperes drain current and 60.00 amperes off-state current, peak

Power Rating Per Characteristic:

100.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0